



DMP6350SQ

60V P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C
2014	$350 \text{m}\Omega$ @ $V_{GS} = -10 \text{V}$	-1.5A
-60V	550mΩ @ V _{GS} = -4.5V	-1.2A

Features and Benefits

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability
- PPAP Capable (Note 4)

Description and Applications

This MOSFET is designed to meet the stringent requirements of Automotive applications. It is qualified to AEC-Q101, supported by a PPAP and is ideal for use in:

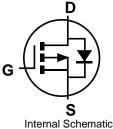
- Backlighting
- Power Management Functions
- DC-DC Converters

Mechanical Data

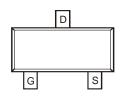
- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound.
 UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Copper Leadframe.
 Solderable per MIL-STD-202, Method 208 (§3)
- Terminals Connections: See Diagram Below
- Weight: 0.009 grams (Approximate)











Top View

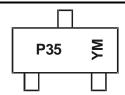
Ordering Information (Note 5)

Part Number	Case	Packaging
DMP6350SQ-7	SOT23	3000/Tape & Reel
DMP6350SQ-13	SOT23	10,000/Tape & Reel

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. Automotive products are AEC-Q101 qualified and are PPAP capable. Refer to https://www.diodes.com/quality/.
- 5. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



 $\begin{array}{l} P35 = Product\ Type\ Marking\ Code\\ YM = Date\ Code\ Marking\\ Y\ or\ \overline{Y} = Year\ (ex:\ F = 2018)\\ M = Month\ (ex:\ 9 = September) \end{array}$

Date Code Kev

- ale code ite								
Year	2015	2016	2017	2018	2019	2020	2021	2022
Code	С	D	Е	F	G	Н	l	J

Month	Jan	Feb	Mar	Apr	May	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Drain-Source Voltage		V_{DSS}	-60	V
Gate-Source Voltage		V_{GSS}	±20	V
Continuous Drain Current (Note 7), V _{GS} = -10V	I _D	-1.5 -1.2	Α	
Pulsed Drain Current (10µs Pulse, Duty Cycle =	1%)	I _{DM}	-6	Α

Thermal Characteristics

Characteristic	Symbol	Value	Unit
Power Dissipation (Note 6)	P _D	0.72	W
Thermal Resistance, Junction to Ambient @T _A = +25°C (Note 6)	$R_{ heta JA}$	176	°C/W
Power Dissipation (Note 7)	P _D	1.17	W
Thermal Resistance, Junction to Ambient @T _A = +25°C (Note 7)	$R_{ heta JA}$	108	°C/W
Thermal Resistance, Junction to Case	$R_{ heta JC}$	34	°C/W
Operating and Storage Temperature Range	T _J , T _{STG}	-55 to +150	°C

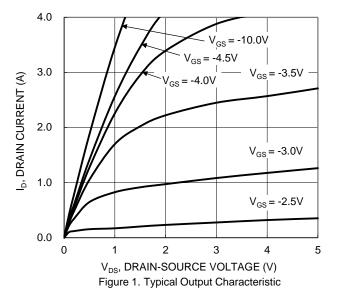
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

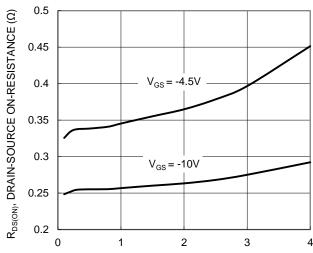
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 8)	Syllibol	IVIIII	тур	IVIAX	Ollit	rest condition
Drain-Source Breakdown Voltage	BV _{DSS}	-60	_	_	V	$V_{GS} = 0V, I_{D} = -250\mu A$
Zero Gate Voltage Drain Current T _J = +25°C	IDSS	_	_	-1.0	μA	V _{DS} = -60V, V _{GS} = 0V
Gate-Source Leakage	I _{GSS}	_	_	±100	nA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 8)	.000		l			1.00 ==01,150 01
Gate Threshold Voltage	V _{GS(TH)}	-1.0	-1.8	-3.0	V	$V_{DS} = V_{GS}, I_{D} = -250 \mu A$
Static Drain-Source On-Resistance	R _{DS(ON)}	_	257 343	350 550	mΩ	$V_{GS} = -10V, I_D = -0.9A$ $V_{GS} = -4.5V, I_D = -0.8A$
Diode Forward Voltage	V _{SD}	_	-0.8	-1.2	V	V _{GS} = 0V, I _S = -1A
DYNAMIC CHARACTERISTICS (Note 9)	1 00		1			7.00 21,10
Input Capacitance	C _{iss}	_	206	_	pF	
Output Capacitance	Coss	_	15	_	pF	$V_{DS} = -30V, V_{GS} = 0V,$ - f = 1.0MHz
Reverse Transfer Capacitance	C _{rss}	_	11	_	pF	71 = 1.0WHZ
Gate Resistance	Rg	_	17	_	Ω	$V_{DS} = 0V$, $V_{GS} = 0V$, $f = 1MHz$
Total Gate Charge (V _{GS} = -4.5V)	Qq	_	2.0	_	nC	
Total Gate Charge (V _{GS} = -10V)	Qg	_	4.1	_	nC	7,, ,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,,
Gate-Source Charge	Q _{gs}	_	0.5	_	nC	$V_{DS} = -30V, I_{D} = -0.9A$
Gate-Drain Charge	Q _{qd}	_	0.8	_	nC	
Turn-On Delay Time	t _{D(ON)}	_	3.6	_	ns	
Turn-On Rise Time	t _R	_	3.8	_	ns	$V_{DD} = -30V, V_{GS} = -10V,$
Turn-Off Delay Time	t _{D(OFF)}	_	12.3	_	ns	$I_D = -1.0A, R_g = 6\Omega$
Turn-Off Fall Time	t _F	_	7.3	_	ns	7
Body Diode Reverse Recovery Time	t _{RR}	_	8.2	_	ns	I _S = -1.0A, di/dt = -100A/μs
Body Diode Reverse Recovery Charge	Q_{RR}	_	2.7	_	nC	$I_S = -1.0A$, di/dt = -100A/ μ s

6. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout.
7. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate. Notes:

Short duration pulse test used to minimize self-heating effect.
 Guaranteed by design. Not subject to product testing.







I_D, DRAIN-SOURCE CURRENT (A) Figure 3. Typical On-Resistance vs. Drain Current and Gate Voltage

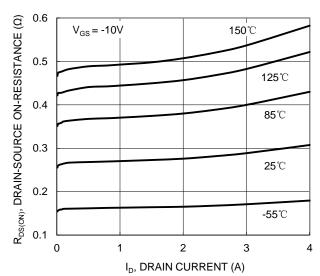
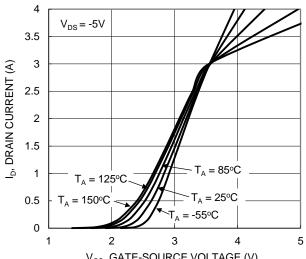


Figure 5. Typical On-Resistance vs. Drain Current and Temperature



V_{GS}, GATE-SOURCE VOLTAGE (V) Figure 2. Typical Transfer Characteristic

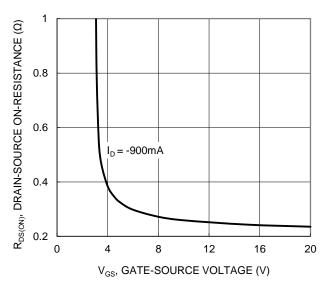


Figure 4. Typical Transfer Characteristic

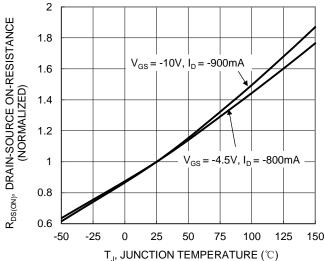


Figure 6. On-Resistance Variation with Junction Temperature



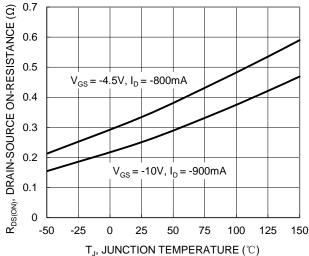
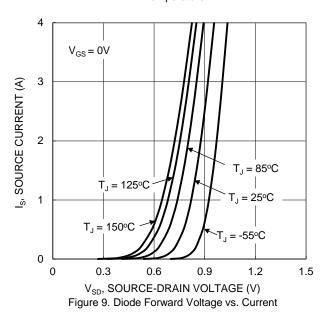


Figure 7. On-Resistance Variation with Junction
Temperature



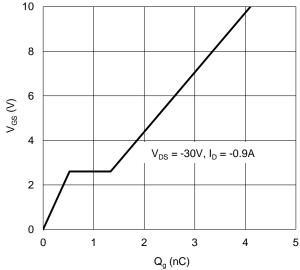


Figure 11. Gate Charge

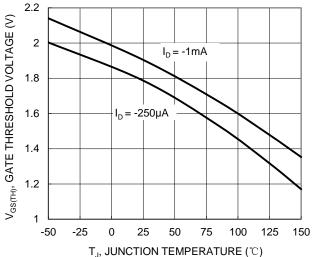
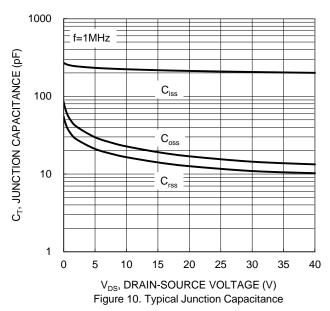


Figure 8. Gate Threshold Variation vs. Junction Temperature



 $\begin{array}{c} \text{TO} \\ \text{R}_{\text{DS(ON)}} \text{Limited} \\ \text{P}_{\text{W}} = 100 \mu \text{S} \\ \text{Single Pulse} \\ \text{DUT on 1*MRP Board} \\ \text{O.001} \\ \text{O.001} \\ \text{O.1} \\ \text{1} \\ \text{10} \\ \text{10}$

Figure 12. SOA, Safe Operation Area



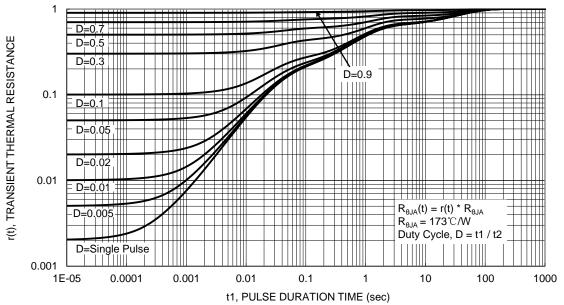
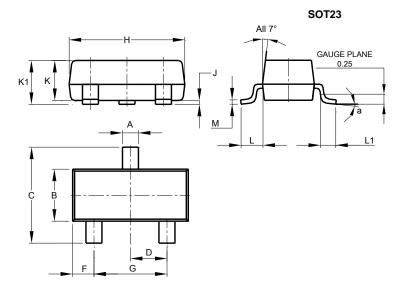


Figure 13. Transient Thermal Resistance



Package Outline Dimensions

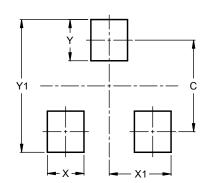
Please see http://www.diodes.com/package-outlines.html for the latest version.



	SOT23									
Dim	Min	Max	Тур							
Α	0.37	0.51	0.40							
В	1.20	1.40	1.30							
С	2.30	2.50	2.40							
D	0.89	1.03	0.915							
F	0.45	0.60	0.535							
G	1.78	2.05	1.83							
Н	2.80	3.00	2.90							
J	0.013	0.10	0.05							
K	0.890	1.00	0.975							
K1	0.903	1.10	1.025							
L	0.45	0.61	0.55							
L1	0.25	0.55	0.40							
М	0.085	0.150	0.110							
а	0°	8°								
All	All Dimensions in mm									

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23

Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Υ	0.9
Y1	2.9



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